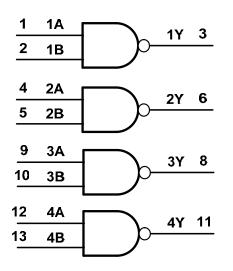


Pin Descriptions

| Pin Number | Pin Name | Function |
|---------------|----------|----------------|
| 1 | 1A | Data Input |
| 2 | 1B | Data Input |
| 3 | 1Y | Data Output |
| 4 | 2A | Data Input |
| 5 | 2B | Data Input |
| 6 | 2Y | Data Output |
| 7 | GND | Ground |
| 8 | 3Y | Data Output |
| 9 | ЗA | Data Input |
| 10 | 3B | Data Input |
| 11 | 4Y | Data Output |
| 12 | 4A | Data Input |
| 13 | 4B | Data Input |
| 14 | Vcc | Supply Voltage |

Logic Diagram



Fuction Table

| Inp | Output | |
|-----|--------|---|
| Α | В | Y |
| L | L | Н |
| L | н | Н |
| н | L | Н |
| н | н | L |



Absolute Maximum Ratings (Note 4) (@T_A = +25°C, unless otherwise specified.)

| Symbol | Parameter | Rating | Unit |
|---|---|------------------------------|------|
| ESD HBM | Human Body Model ESD Protection | 2 | KV |
| ESD CDM | Charged Device Model ESD Protection | 1 | KV |
| ESD MM | Machine Model ESD Protection | 200 | V |
| V _{CC} | Supply Voltage Range | -0.5 to 6.5 | V |
| VI | Input Voltage Range | -0.5 to 6.5 | V |
| Vo | Voltage applied to output in high impedance or IOFF state | -0.5 to 6.5 | V |
| Vo | Voltage applied to output in high or low state | -0.3 to V _{CC} +0.5 | V |
| I _{IK} | Input Clamp Current VI < 0 | -50 | mA |
| loк | Output Clamp Current V _O < 0 | -50 | mA |
| Io | Continuous output current | ±50 | mA |
| I _{CC} , I _{GND} | Continuous current through Vcc or GND | ±100 | mA |
| T _J Operating Junction Temperature | | -40 to 150 | °C |
| T _{STG} Storage Temperature | | -65 to 150 | °C |
| P _{TOT} Total Power Dissipation | | 500 | mW |

Note: 4. Stresses beyond the absolute maximum may result in immediate failure or reduced reliability. These are stress values and device operation should be within recommend values.

Recommended Operating Conditions (Note 5) (@T_A = +25°C, unless otherwise specified.)

| Symbol | Parameter | Conditions | Min | Max | Unit |
|-----------------|------------------------------------|---------------------------------------|------|-----------------|------|
| V _{CC} | Supply Voltage | | 1.65 | 5.5 | V |
| VI | Input Voltage | | 0 | 5.5 | V |
| | Output Maltana | Active Mode | 0 | V _{CC} | V |
| Vo | Output Voltage | V _{CC} = 0V; Power Down Mode | 0 | 5.5 | V |
| A . / A \ / | Input transition rise or fall rate | V _{CC} = 1.65V to 2.7V | | 20 | ns/V |
| Δt/ΔV | | V _{CC} = 2.7V to 3.6V | | 10 | |
| T _A | Operating free-air temperature | | -40 | +125 | °C |

Notes: 5. Unused inputs should be held at $V_{\mbox{CC}}$ or Ground.



Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| . | | Terror | | $T_{A} = -40^{\circ}$ | C to +85°C | T _A = -40°C | to +125°C | |
|------------------|----------------------------------|--|-----------------|------------------------|------------------------|------------------------|------------------------|------|
| Symbol Parameter | | Test Conditions | V _{cc} | Min | Max | Min | Max | Unit |
| | | | 1.65V to 1.95V | 0.65 X V _{CC} | | 0.65 X V _{CC} | | |
| VIH | High-level Input | | 2.3V to 2.7V | 1.7 | | 1.6 | | V |
| | Voltage | | 2.7 V to 3.6V | 2.0 | | 2.0 | | |
| | | | 1.65V to 1.95V | | 0.35 X V _{CC} | | 0.35 X V _{CC} | |
| VIL | Low-level input | | 2.3V to 2.7V | | 0.7 | | 0.7 | V |
| | voltage | | 2.7V to 3.6V | | 0.8 | | 0.8 | |
| | | I _{OH} = -100μA | 1.65V to 3.6V | V _{CC} -0.2 | | $V_{CC} - 0.3$ | | |
| | | I _{OH} = -4mA | 1.65V | 1.2 | | | | |
| ,, High Level | I _{OH} = -8mA | 2.3V | 1.9 | | | | V | |
| V _{OH} | Output Voltage | 10 | 2.7V | 2.2 | | 2.05 | | v |
| | | I _{OH} = -12mA | 3.0V | 2.3 | | 2.1 | | |
| | | I _{OH} = -24mA | 3.0V | 2.2 | | 2.0 | | |
| | | I _{OH} = 100μA | 1.65V to 3.6V | | 0.2 | | 0.3 | |
| | | I _{OH} = 4mA | 1.65V | | 0.45 | | 0.6 | |
| | High-level | I _{OH} = 8mA | 2.3V | | 0.70 | | 0.85 | V |
| V _{OL} | Output Voltage | 1. 10m 4 | 2.7V | | 0.40 | | 0.6 | v |
| | | I _{OH} = 12mA | 3.0V | | 0.55 | | 0.6 | |
| | | I _{OH} =-24mA | 3.0V | | 0.55 | | 0.6 | |
| li - | Input Current | $V_1 = GND$ to 5.5V | 3.6V | | ±5 | | ±20 | μA |
| I _{OFF} | Power Down Leakage Current | $V_1 \text{ or } V_0 = 0V$ to 3.6V | 0 | | 10 | | 20 | μA |
| I _{CC} | Supply Current | $V_{I} = GND \text{ or } V_{CC}$ $I_{O}=0$ | 3.6V | | 10 | | 40 | μA |
| ΔI _{CC} | Additional Supply Current | One input at V _{CC} – 0.6V Other at Vcc or Gnd. | 2.7V to 3.6V | | 500 | | 5000 | μA |

Switching Characteristics

| Cumhal | Test | | st v | | T _A = 25°C | | -40°C to 85°C | | -40°C to 125°C | | 11 |
|-------------------|---|-----------------|---------------|-----|-----------------------|------|---------------|------|----------------|------|----|
| Symbol Parameter | Conditions | V _{cc} | Min | Тур | Max | Min | Max | Min | Max | Unit | |
| | | | 1.65V to1.95V | 1.0 | 6.0 | 12.0 | 1.0 | 12.5 | 1.0 | 14.0 | |
| Propagation | — | 2.3V to 2.7V | 1.0 | 4.6 | 5.9 | 1.0 | 6.4 | 1.0 | 7.9 | | |
| t _{PD} | Delay A _N or B _N to Y _N | Figure 1 | 2.7V | 1.0 | 4.3 | 4.9 | 1.0 | 5.1 | 1.0 | 6.5 | ns |
| to Y _N | | 3V to 3.6V | 1.0 | 3.5 | 4.1 | 1.0 | 4.3 | 1.0 | 5.5 | | |
| tauro | Output Skew | | 3V to 3.6V | | | | | 1.0 | | 1.5 | 20 |
| tsk(0) | Time | | 30 10 3.60 | | | | | 1.0 | | 1.5 | ns |



Operating Characteristics (@T_A = +25°C, unless otherwise specified.)

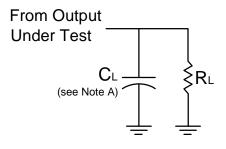
| I | Parameter | Test Conditions | V _{CC} = 1.8V Typ | V _{CC} = 2.5V Typ | V _{cc} = 3.3V Typ | Unit |
|-----------------|---|-------------------------|-------------------------------|-------------------------------|-------------------------------|------|
| C _{pd} | Power dissipation capacitance per gate | f = 10 MHz | 17 | 17 | 18 | pF |
| CI | Input Capacitance | $V_I = V_{CC} - or GND$ | 4 | 4 | 4 | pF |

Package Characteristics

| Symbol | Parameter | Test Conditions | V _{cc} | Min | Тур | Max | Unit |
|----------------------|---------------------|-----------------|-----------------|-----|-----|-----|------|
| 0 | Thermal Resistance | SO-14 | (Note 6) | | TBD | | °C/W |
| θ_{JA} | Junction-to-Ambient | TSSOP-14 | | | 159 | | |
| 0 | Thermal Resistance | SO-14 | (Note 6) | | TBD | | °C/W |
| θ_{JC} | Junction-to-Case | TSSOP-14 | | | 25 | | |

Note: 6. Test condition for SO-14 and TSSOP-14 : Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.

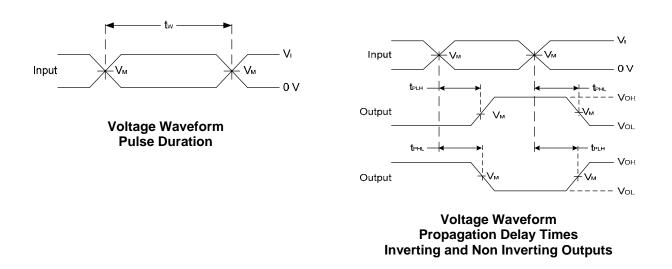
Parameter Measuement Information



| V. | Inp | outs | V | C | R∟ | |
|------------|-----------------|--------------------------------|-------------------------------|------|------|--|
| Vcc | VI | t _r /t _f | t _f V _M | 5 | ΝL | |
| 1.8V±0.15V | V _{CC} | ≤2ns | V _{CC} /2 | 30pF | 1ΚΩ | |
| 2.5V±0.2V | V _{CC} | ≤2ns | V _{CC} /2 | 30pF | 500Ω | |
| 2.7V | 2.7V | ≤2.5ns | 1.5V | 50pF | 500Ω | |
| 3.3V±0.3V | 2.7V | ≤2.5ns | 1.5V | 50pF | 500Ω | |

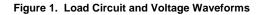


Parameter Measuement Information (cont.)

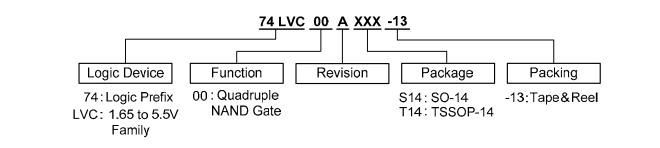


Notes: A . Includes test lead and test apparatus capacitance.

- B. All pulses are supplied at pulse repetition rate < 10 MHz
 C. Inputs are measured separately one transition per measurement
- D. tPLH and tPHL are the same as tPD



Ordering Information



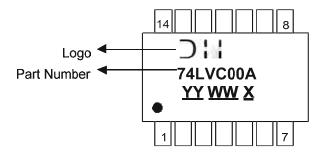
| | Part | Package | Packaging | 13" Tape and Reel | | |
|-----|----------------|---------|-----------|-------------------|--------------------|--|
| | Number | Code | (Note 7) | Quantity | Part Number Suffix | |
| Pb, | 74LVC00AS14-13 | S14 | SO-14 | 2500/Tape & Reel | -13 | |
| PD. | 74LVC00AT14-13 | T14 | TSSOP-14 | 2500/Tape & Reel | -13 | |

Notes: 7. The taping orientation and tape details can be found at http://www.diodes.com/datasheets/ap02007.pdf



Marking Information

(1) SO-14, TSSOP-14

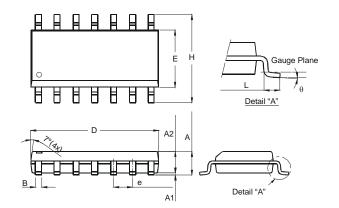


YY: Year: 08, 09, 10~ WW: Week: 01~52; 52 represents 52 and 53 week \underline{X} : Internal Code

| Part Number | Package |
|-------------|----------|
| 74LVC00AS14 | SO-14 |
| 74LVC00AT14 | TSSOP-14 |

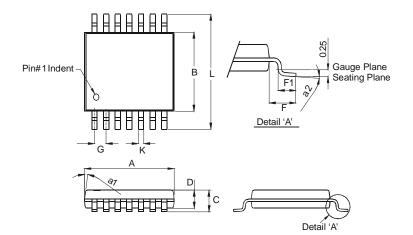
Package Outline Dimensions (All dimensions in mm.)

Package Type: SO-14



| | SO-14 | |
|--------|----------|---------|
| Dim | Min | Max |
| Α | 1.47 | 1.73 |
| A1 | 0.10 | 0.25 |
| A2 | 1.45 | Тур |
| В | 0.33 | 0.51 |
| D | 8.53 | 8.74 |
| ш | 3.80 | 3.99 |
| e | 1.27 | Тур |
| H | 5.80 | 6.20 |
| L | 0.38 | 1.27 |
| θ | 0° | 8° |
| All Di | mensions | s in mm |

Package Type: TSSOP-14



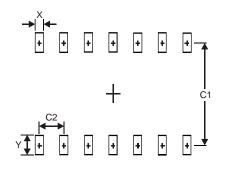
| TSSOP-14 | | | |
|----------------------|----------|------|--|
| Dim | Min | Max | |
| a1 | 7° (4X) | | |
| a2 | 0° | 8° | |
| Α | 4.9 | 5.10 | |
| В | 4.30 | 4.50 | |
| С | | 1.2 | |
| D | 0.8 | 1.05 | |
| F | 1.00 Тур | | |
| F1 | 0.45 | 0.75 | |
| G | 0.65 Тур | | |
| Κ | 0.19 | 0.30 | |
| Ĺ | 6.40 Typ | | |
| All Dimensions in mm | | | |



74LVC00A

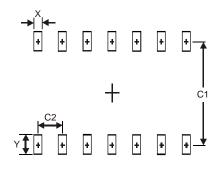
Suggested Pad Layout





| Dimensions | Value (in mm) |
|------------|---------------|
| Х | 0.60 |
| Y | 1.50 |
| C1 | 5.4 |
| C2 | 1.27 |

Package Type: TSSOP-14



| Dimensions | Value (in mm) |
|------------|---------------|
| Х | 0.45 |
| Y | 1.45 |
| C1 | 5.9 |
| C2 | 0.65 |



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